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	Applicant(s): Hai-Zhi SONG	
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U.S. PATENT DOCUMENTS

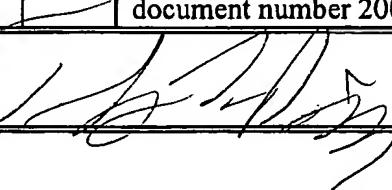
Examiner Initial	Document No.	Name	Date	Class	Subclass	Filing Date (If appropriate)
TD	AA 6,335,245	B.G. Park et al.	01/01/02			
	AB	—	—	—	—	

FOREIGN PATENT DOCUMENTS

		Document No.	Date	Country	Translation (Yes or No)
TD	AC	6-196720	07/15/94	Japan	Yes-Abstract
TD	AD	2002-518851	06/25/02	Japan	No-Corresponds to WO 99/66562
TD	AE	10-303408	11/13/98	Japan	Yes-Abstract
TD	AF	11-150261	06/02/99	Japan	Yes-Abstract
TD	AG	5-211342	08/20/93	Japan	Yes-Abstract
TD	AH	2000-91451	03/31/00	Japan	Yes-Abstract
TD	AI	2001-7315	01/12/01	Japan	Yes-Abstract

OTHER DOCUMENTS

TD	AJ	U.F. Keyser et al.; "Fabrication of a single-electron transistor by current-controlled local oxidation of a two-dimensional electron system"; <i>Applied Physics Letters</i> ; Vol. 76; No. 4; January 24, 2000; pp. 457-459.
TD	AK	T. Fujisawa et al.' "Transient current spectroscopy of a quantum dot in the Coulomb blockade regime"; <i>Physical Review B</i> ; Vol. 63; 081304(R); 2001; 4 pages.
TD	AL	Abstract of WO 99/66562 published December 23, 1999/Corresponds to Japanese document number 2002-518851.

Examiner  Date Considered 12/12/04